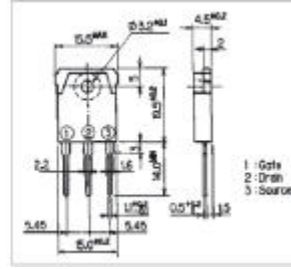
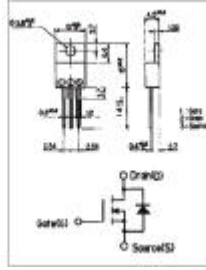
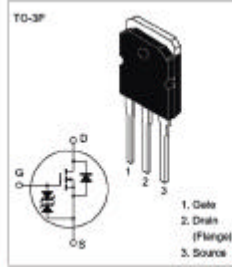
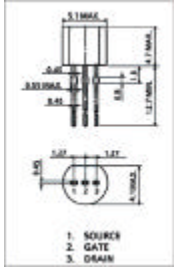


SEMICONDUCTORS-DISCRETES

2SK-系列功率場效應電晶體 2SK-Series J-FET Transistors

詳細產品規格--請點擊www.100y.com.tw



PartNo	ProductNo.	Manuf.	Description	Pol	Vdgr	Vgss	Pd(max)	Id(max)	Pins/Package
14862	2SJ449	NEC	TO-220	P	250V	±30V	35W	6A	3P/TO-220
15942	2SK1017		N-channel silicon power MOSFET	N	450V		150W	20A	3P/TO-3PN
15662	2SK1020	FUJITSU	N-channel silicon power MOSFET	N	500V	±30V	300W	30A	3P/TO-264AA
15569	2SK1045	MITSUBISHI	TRANSISTOR	N	8000V	±30V	150W	5A	3P/TO-3PN
20243	2SK1061	TOSHIBA	N channel field effect transistor	N-Ch	60V	±20V	300mW	200mA	TO-92
15657	2SK1081	Fairchild	N-channel silicon power MOSFET	N	800V	±30V	125W	7A	TO-3P(N)
15666	2SK1117	TOSHIBA	N-channel silicon power MOSFET	N	600V		100W	6A	TO-220
15665	2SK1119	TOSHIBA	Silicon N channel field effect transistor for high speed,	N	1000V	±20V	100W	4A	TO-220
15127	2SK1120	TOSHIBA	Silicon N channel field effect transistor for high speed,	N	1000V	±20V	150W	8A	3P/TO-3PN
14852	2SK1153	HITACHI	Power switching MOSFET	N	450V	±30V	30W	3A	3P/TO-220AB
14853	2SK1155	HITACHI	Power switching MOSFET	N	450V	±30V	50W	5A	3P/TO-220AB
14854	2SK1157	HITACHI	Power switching MOSFET	N	450V	±30V	60W	7A	3P/TO-220AB
6013	2SK117-GR	TOSHIBA	Silicon N Channel Junction Type	N	-5V	1.5V	300mW	10mA	3P/TO-92
6031	2SK1221		N-channel silicon power MOSFET	N	250V	±30V	80W	10A	3P/TO-220AB
14855	2SK1313S	HITACHI	Power switching MOSFET	N	450V	±30V	50W	±0.1A	D2PAK
16620	2SK1339	HITACHI	High speed power switching	N	900V	±30V	80W	3A	3P/TO-3PN
6033	2SK1341		Power switching MOSFET	N	900V	±30V	100W	6A	3P/TO-3PN
15663	2SK1358	TOSHIBA	Silicon N-channel MOS type	N	900V	±30V	150W	9A	TO-3P
19459	2SK1385	Fuji Elect	Power switching MOSFET	N	100V	±20V	900mW	600mA	3P/TO-3PN
14856	2SK1403	HITACHI	Power switching MOSFET	N	650V	±30V	100W	±0.1A	3P/TO-3PN
16628	2SK1500	NEC	N-Channel	N	450V	±30V	125W	18A	3P/TO-247
15664	2SK1507	FUJITSU	Fuji power MOS-FET	N	600V	±30V	50W	9A	TO-220
6036	2SK1529		Silicon N channel field effect transistor for high power amplifier applications	N	180V	±20V	120W	10A	3P/TO3PN
14858	2SK1667	HITACHI	Power switching MOSFET	N	250V	±30V	50W	7A	3P/TO-220AB
24058	2SK1719		Power MOSFET						TO-252
15667	2SK1794	NEC	N-MOS/600V/6A/100W	N	900V		150W	5A	TO-3P
15646	2SK1940	Fairchild	power amplifier applications	N	600V	600V	55W	12A	3P/TO-3PN
23663	2SK1994	NEC	Power MOSFET	N-CHANNEL	10V		30W	2A	TO-220
13607	2SK2134	NEC	N-channel power MOS FET for high voltage switching applications	N-Ch	10V	10V	70W	7A	TO-220
14851	2SK2161-T	SANYO	N-channel MOS silicon FET, very high-speed switching application	N	200V	±20V	70W	9A	3P/TO-220ML
17073	2SK2275	NEC	N-channel	N	900V	10V	35W	6A	TO-220F
13621	2SK2485	NEC	Nch power MOSFET MP-88900V/6A	N	900V	±30V	100W	3.0A	TO-247
17074	2SK2662	TOSHIBA	DC/DC Converter, Relay Drive and Motor Drive Applications	N	500V	±30V	35W	5A	TO-220
10949	2SK2698	TOSHIBA	Silicon N channel field effect transistor	N	500V	±30V	150W	1mA	3P/TO3PN
23662	2SK2837	TOSHIBA	N-Ch. MOSFET	N-Ch	500V	±30V	150W	20A	3P/TO-3
4865	2SK30A		N CHANNEL JUNCTION TYPE	N	-5V	-5V	100mW	10mA	3P/TO-92
17874	2SK400	NEC	N-FET	N	200V	±20V	100W	8A	TO-218
14859	2SK513	HITACHI	Silicon N-Channel MOS FET	N	800V	±20V	60W	3A	3P/TO-220
6024	2SK725		SILICON POWER MOS-FET	N	500V	±20V	125W	15mA	3P/TO-3PN
15655	2SK727	FUJITSU	Power MOS-FET	N	900V	±20V	125W	5A	TO-3P(N)
16581	2SK787	NEC	FET, Power	N	900V		120W	8A	TO-3P
6026	2SK793	TOSHIBA	POWER MOSFET	N	850V	±20V	150W	5A	3P/TO-220
15944	2SK899	FUJITSU	N-CHANNEL	N	500V	±20V	125W	18A	TO-3P
18466	2SK941	TOSHIBA	Power switching MOSFET	N	100V	±20V	900mW	600mA	3P/TO-3PN
12674	2SK956		Power switching MOSFET	N	900V	±30V	100W	6A	3P/TO-3PN
15658	2SK962	FUJITSU	N-channel	N	900V	±30V	150W	8A	TO-3P(N)
27026	IRF530A	Fairchild	Advanced Power MOSFET	N-Ch	100V	0.16	79W	14A	3P/TO-220AB

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